1449A/PTO Rev. 10/95		U.S. Department of Commerce Patent and Trademark Office	Complete If Known			
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LIST OF PRIOR ART CITED				Filing Date	06-23-03	
BY APPLICANT				First Named Inventor	Yoshi Ono	
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(use as many sheets as necessary)			ecessary) `	Examiner Name	Khiem D. Ngryer	
Sheet	1	of	. 1	Attorney Docket No.	SLA.0669 0 0	

U.S. PATENT DOCUMENTS					
Examiner Initials	Cite No.'	U.S. Patent Document Kind Number Code ² (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YY	Pages, Columns, Lines, Where Relevant Passages or Figures Appear
K.N.		6,274,510 B1	Wilk et al.	08-14-01	
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FOREIGN PATENT DOCUMENTS							
Examiner Initials	Cite No.1	Foreign Patent Dcument	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YY	Pages, Columns, Lines, Where Relevant Passages or Figures Appear	1.0	
		Office 3 Number Kind					
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OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS					
Examiner Initials	Cite No.'	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, country where published, source.	T²		
K.N.		K. Watanabe et al., Controlling the concentration and position of nitrogen in ultrathin oxynitride films formed by using oxygen and nitrogen radicals, Appl. Phys. Lett. 76, 2940 (2000).			
K.n.		J. Joseph et al., A kinetics study of the electron cyclotron resonance plasma oxidation of silicon, J. Vac. Sci. Technol. B10, 611 (1992).			

Examiner	4.0	Date	
Signature	Klysematuren	Considered	03/04/04

Examiner. Initial if reference considered, whether of not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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